## Focused Ion Beam Induced Processing applied to Nanosuperconductivity

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### Outline

- **1) Introduction to the Superconductivity**
- 2) Focused Ion Beam Induced Processing (FIBIP)
  - Nanolithography: FIB Induced Milling
  - Nanofabrication: FIB Induced Deposition
- 3) Focused Ion Beam Induced Processing (FIBIP) applied to the nanosuperconductivity
  - Nanolithography: FIB Induced Milling applied to the nanosuperconductivity

- Nanofabrication: FIB Induced Deposition applied to the nanosuperconductivity

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#### Superconducting materials - strengths



#### H. Kamerlingh Onnes, 1911



#### Perfect conductor

#### Superconducting materials - weaknesses





#### Temperature



### Magnetic field



#### Superconducting materials - applications



High energy physics



Medical field



Power generation



Power quality and storage



Transportation

#### Superconducting materials - origin



### Superconductivity – Phase diagram

#### **Superconductor Type I**



### Superconductivity – Phase diagram

#### **Superconductor Type II**



### Type II Superconductor – SC vortex



### Type II Superconductor – vortex lattice

#### **Abrikosov vortex lattice**



$$d_{\Delta} = \left(\frac{4}{3}\right)^{1/4} \left(\frac{\phi_0}{B}\right)^{1/2}$$

### Type II Superconductor – vortex dynamics



### Nanosuperconductivity

#### $\xi$ : superconducting coherence length



Dissipation-free energy state

Quasi 1D SC nanowire arrays

• Quantum dynamics of a single vortex





K. Xu et al., Nano Letters (2008)



A. Wallraff et al., Nature (2005)

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### Focused Ion Beam Induced Processing (FIBIP)

#### Nanoscience and Nanotechnology



### Focused Ion Beam Induced Processing (FIBIP)



### Focused ion beam (FIB)



#### **UNDERLYING IDEA:**

 $\lambda \sim h/mv$ , short  $\lambda$  (< 1 nm), accelerating the ions under high voltage (up to 50 kV).



### Focused ion beam (FIB)



#### **UNDERLYING IDEA:**

 $\lambda \sim h/mv$ , short  $\lambda$  (< 1 nm), accelerating the ions under high voltage (up to 50 kV).

#### **CONFIGURATIONS**:

-Imaging and Analysis

-Nanolithography: FIB Induced Milling

-Nanofabrication: FIB Induced Deposition

#### FIBIP

J. Gierak, Nanofabrication 1 (2014) 35

### Ga<sup>+</sup> focused ion beam column

- Voltage: 0.5-50 kV
- Beam current: 1pA-20nA
- Condenser lens
- Deflection lens
- Objective lens
- Apertures and stigmators
- "Beam blanker"



J. Gierak, Nanofabrication 1 (2014) 35

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### Focused ion beam sources

#### **1. Liquid metal ion source (LMIS):**

- generally based on gallium, with resolution of 5 nm
- low melting point and vapour pressure
- long life time: 1500 hours
- viscous behaviour on a W tip
- source brightness: 10<sup>8</sup> A/cm<sup>2</sup>





**Electrical feed-throughs** 

### Focused ion beam sources

#### 2. Gas ion source (GIS):

- based on He and Neon
- probe size≈ 0.3 nm

- source brightness: 10<sup>9</sup> A/cm<sup>2</sup> (30 times better than the Schottky FEG electron source and 500 times better than LMIS)



### **Commercial FIB configurations**

#### **One single FIB**



#### FIB + SEM = Dual Beam



#### **Three FIBs = Multi FIB**



### He<sup>+</sup>/Ne<sup>+</sup> focused ion beam column



#### • Advantages:

- higher resolution imaging, 2 nm
- lower proximity effect
- higher sensitivity
- milling of sub-10 nm structures
- growth of sub-10 nm structures

### Interaction of ions with solid materials



Shorubalko, book chapter in "Helium Ion Microscopy", Springer 2016

### Interaction of ions with solid materials



Shorubalko, book chapter in "Helium Ion Microscopy", Springer 2016

## Interaction of ions vs. electrons with solid materials



The interaction of ions with matter is much shorter than in the case of electrons, thus being confined closer to the surface.

### Focused Ion Beam Induced Processing (FIBIP)

#### FIBIP:

- Nanolithography: FIB Induced Milling
- Nanofabrication: FIB Induced Deposition



Philip J.W. Moll , Annual Review of Condensed Matter Physics 2017

### Nanolithography: FIB induced milling

#### **Physical process: transfering momentum**



Utke, JVSTB 2008

### Nanolithography: FIB induced milling



### Nanofabrication: FIB Induced Deposition



PHYSICAL REVIEW

VOLUME 45

#### Insulating Films Formed Under Electron and Ion Bombardment

R. LARIVIERE STEWART, Ryerson Physical Laboratory, University of Chicago (Received December 18, 1933)

In an evacuated tube in which the slightest traces of organic vapors may occur, even with liquid air cooling, insulating layers are formed on surfaces subject to electron or canal-ray bombardment. These layers may be attributed to carbon compounds, and their formation is related to the polymerization of organic vapors by electrical discharges,  $\alpha$ -particles, and ultraviolet light. The simple iondeposition theory is inadequate as the layers are formed only at the point of impact of the rays on the surface. Electrical resistances and break-down potentials were observed for several films. The importance of these deposits in general experimental practice, such as the photometry of mass-spectra, is pointed out, and, amongst others, cases are cited of their influence producing contact potentials, pseudo high vacua, erroneous photographic recording and differential condensation of vapors upon previously bombarded surfaces.

### Nanofabrication: FIB Induced Deposition

#### Focused ion beam induced deposition (FIBID)



Utke, J. Vac. Sci. Technol. B, 2008

**Ga<sup>+</sup> FIBID** 

**APPLICATIONS:** integrated circuit modification (circuit edit), mask repair, fabrication of small electrical contacts... Although generally the metallic content is not high enough (at. % 40-80) impairing the applications of the technique.

### Nanofabrication: FIB Induced Deposition

#### Focused ion beam induced deposition (FIBID)



Sadki, APL 2004

Ga<sup>+</sup> FIBID lateral resolution: **19 nm** 



W. Li, Micr. Eng. 2011

He<sup>+</sup> FIBID lateral resolution: **10 nm** 



H. Wu, J. Mat. Sci. 2014



Morita et al. 2003

Giannuzzi et al. 2005

#### W, Pt, Co, Pd, C,... metals, ferromagnets, superconductors

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### Nanolithography: *FIB Induced Milling* applied to nanosuperconductivity

### Example of vortex pinning in high-temperature YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub> thin films patterned with an array of antidots



A. Palau et al. PHYSICAL REVIEW B 85, 012502 (2012)

### Nanolithography: *FIB Induced Milling* applied to nanosuperconductivity

#### **Example of structures for intrinsic Josephson physics**



S. Ooi et al. Phys. Rev. Lett. 2002

Superconducting deposits grown by Ga<sup>+</sup> FIBID



Sadki, APL 2004

- Type II superconductor
- T<sub>c</sub> ~ 5 K - B<sub>c2</sub> (0K) > 9 T

### Example of <u>superconducting</u> nanowires: WC Ga<sup>+</sup> FIBID (a) (b) W nanostructu 50 SiO<sub>2</sub> Pt FIBID V-10 µm Ti

R. Córdoba et al., Nature Comm. 2013

**Example of** <u>superconducting</u> nanowires: WC Ga<sup>+</sup> FIBID

**Re-entrance of the superconductivity** 



R. Córdoba et al., Nature Comm. (2013)

Example of 3D SC quantum interference device (SQUID) pickup loops: WC Ga<sup>+</sup> FIBID

W-C NWs grown by Ga<sup>+</sup> FIBID: T<sub>c</sub>~ 5.4 K, J<sub>c</sub>(4.2K)~ 0.4 MA/cm<sup>2</sup>



Romans et al., Appl. Phys. Lett. 97, 222506 (2010)

### Nanolithography and Nanofabrication: FIBIP applied to nanosuperconductivity

#### Example of 3D <u>superconducting</u> hollow nanowires: WC He<sup>+</sup> FIBID



#### R. Córdoba et al., Nano Letters 2018

### Nanolithography and Nanofabrication: FIBIP applied to nanosuperconductivity

#### Example of 3D superconducting hollow nanowires: WC He<sup>+</sup> FIBID



30 kV		
1.15 pA	1.34 pA	
32 nm	70 nm	
21.2 nm/s	6.4 nm/s	
0.015 μm³/nC	0.018 μm³/nC	

<b>3D WC nanowires:</b>	Volume per dose:
- <i>d</i> down to <b>32 nm</b>	- similar to Ga <sup>+</sup> FIBID.
- AR ( <i>I/d</i> )≈ 200	- 10 <sup>3</sup> times higher than FEBID

Smallest hollow nanowire has been fabricated so far.

### Nanolithography and Nanofabrication: FIBIP applied to nanosuperconductivity

Example of 3D superconducting hollow nanowires: WC He<sup>+</sup> FIBID



R. Córdoba et al., Nano Letters 2018

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# Thank you very much for your attention